

**TO - 92 BIPOLAR TRANSISTORS
TRANSISTOR(PNP)**

FEATURES

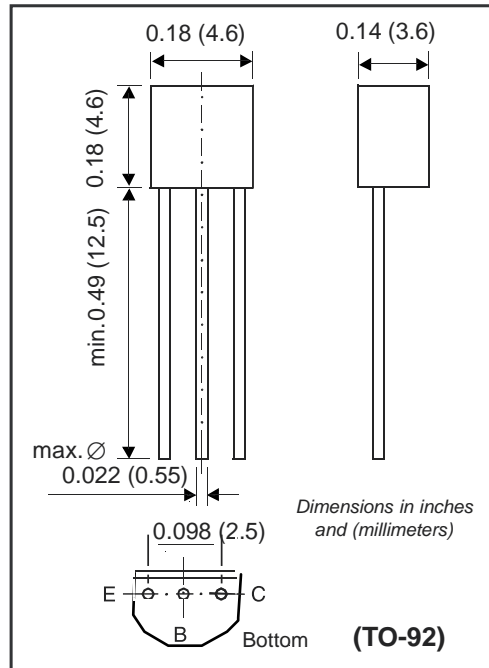
- * Power dissipation
P_{CM}: 0.6 W(T_{amb}=25°C)
- * Collector current
I_{CM}: -0.6 A
- * Collector-base voltage
V_{(BR)CBO}: -40 V
- * Operating and storage junction temperature range
T_J, T_{stg}: -55°C to +150°C

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: UL 94V-O rate flame retardant
- * Lead: MIL-STD-202E method 208C guaranteed
- * Mounting position: Any
- * Weight: 0.008 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.



MAXIMUM RATINGS (@ T_A = 25°C unless otherwise noted)

RATINGS	SYMBOL	VALUE	UNITS
Max. Steady State Power Dissipation ⁽¹⁾ @T _A =25°C Derate above 25°C	P _D	600	mW
Max. Operating Temperature Range	T _J	150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (@ T_A = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS
Thermal Resistance Junction to Ambient	R _{θJA}	-	-	417	°C/W

Notes :1. Alumina=0.4*0.3*0.024in,99.5% alumina
2. "Fully ROHS Compliant", "100% Sn plating (Pb-free)".

ELECTRICAL CHARACTERISTICS (@TA=25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage(1) ($I_C = -1.0 \text{ mAdc}$, $I_B = 0$)	$V_{(BR)CEO}$	-40	-	Vdc
Collector-Base Breakdown Voltage ($I_C = -0.1 \text{ mAdc}$, $I_E = 0$)	$V_{(BR)CBO}$	-40	-	Vdc
Emitter-Base Breakdown Voltage ($I_E = -0.1 \text{ mAdc}$, $I_C = 0$)	$V_{(BR)EBO}$	-5.0	-	Vdc
Base Cutoff Current ($V_{CE} = -35 \text{ Vdc}$, $V_{BE(off)} = -0.4 \text{ Vdc}$)	I_{BEV}	-	-0.1	μAdc
Collector Cutoff Current ($V_{CE} = -35 \text{ Vdc}$, $V_{EB} = -0.4 \text{ Vdc}$)	I_{CEX}	-	-0.1	μAdc

ON CHARACTERISTICS (1)

DC Current Gain ($I_C = -0.1 \text{ mAdc}$, $V_{CE} = -1.0 \text{ Vdc}$) ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -1.0 \text{ Vdc}$) ($I_C = -10 \text{ mAdc}$, $V_{CE} = -1.0 \text{ Vdc}$) ($I_C = -150 \text{ mAdc}$, $V_{CE} = -2.0 \text{ Vdc}$) ($I_C = -500 \text{ mAdc}$, $V_{CE} = -2.0 \text{ Vdc}$)	hFE	30	-	-
		60	-	
		100	-	
		100	300	
		20	-	
Collector-Emitter Saturation Voltage (1) ($I_C = -150 \text{ mAdc}$, $I_B = -15 \text{ mAdc}$) ($I_C = -500 \text{ mAdc}$, $I_B = -50 \text{ mAdc}$)	$V_{CE(sat)}$	-	-0.4	Vdc
		-	-0.75	
Base-Emitter Saturation Voltage (1) ($I_C = -150 \text{ mAdc}$, $I_B = -15 \text{ mAdc}$) ($I_C = -500 \text{ mAdc}$, $I_B = -50 \text{ mAdc}$)	$V_{BE(sat)}$	-0.75	-0.95	Vdc
		-	-1.3	

SMALL-SIGNAL CHARACTERISTICS

Current-Gain-Bandwidth Product ($I_C = -20 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$, $f = 100 \text{ MHz}$)	f_T	200	-	MHz
Output Capacitance ($V_{CB} = -10 \text{ Vdc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$)	C_{cb}	-	8.5	pF
Input Capacitance ($V_{EB} = -0.5 \text{ Vdc}$, $I_C = 0$, $f = 1.0 \text{ MHz}$)	C_{eb}	-	30	pF
Input Impedance ($V_{CE} = -10 \text{ Vdc}$, $I_C = -1.0 \text{ mAdc}$, $f = 1.0 \text{ kHz}$)	h_{ie}	1.5	15	kohms
Voltage Feedback Ratio ($V_{CE} = -10 \text{ Vdc}$, $I_C = -1.0 \text{ mAdc}$, $f = 1.0 \text{ kHz}$)	h_{re}	0.1	8.0	$\times 10^{-4}$
Small-Signal Current Gain ($V_{CE} = -10 \text{ Vdc}$, $I_C = -1.0 \text{ mAdc}$, $f = 1.0 \text{ kHz}$)	h_{fe}	60	500	-
Output Admittance ($V_{CE} = -10 \text{ Vdc}$, $I_C = -1.0 \text{ mAdc}$, $f = 1.0 \text{ kHz}$)	h_{oe}	1.0	100	μmhos

SWITCHING CHARACTERISTICS

Delay Time	$(V_{CC} = -30 \text{ Vdc}$, $V_{EB} = -2.0 \text{ Vdc}$, $I_C = -150 \text{ mAdc}$, $I_{B1} = -15 \text{ mAdc}$)	t_d	-	15	ns
Rise Time		t_r	-	20	
Storage Time	$(V_{CC} = -30 \text{ Vdc}$, $I_C = -150 \text{ mAdc}$, $I_{B1} = I_{B2} = -15 \text{ mAdc}$)	t_s	-	225	ns
Fall Time		t_f	-	30	

Note : Pulse Test: Pulse Width \leq 300ms,Duty Cycle \leq 2.0%

RATING AND CHARACTERISTICS CURVES (2N4403)

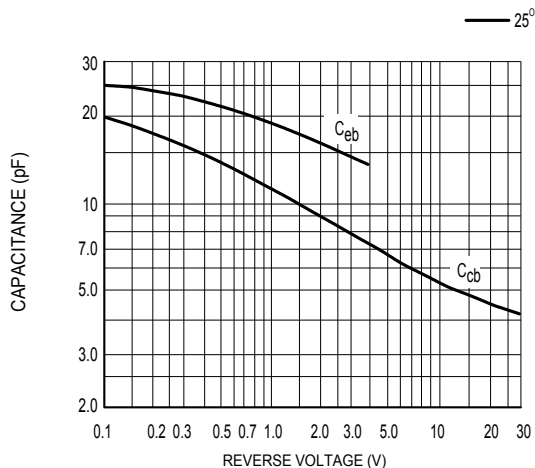


Figure 1. Capacitances

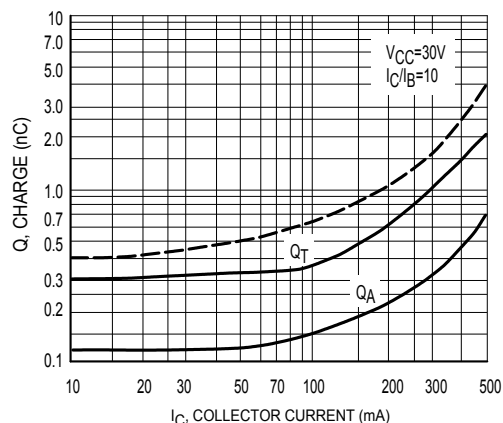


Figure 2. Charge Data

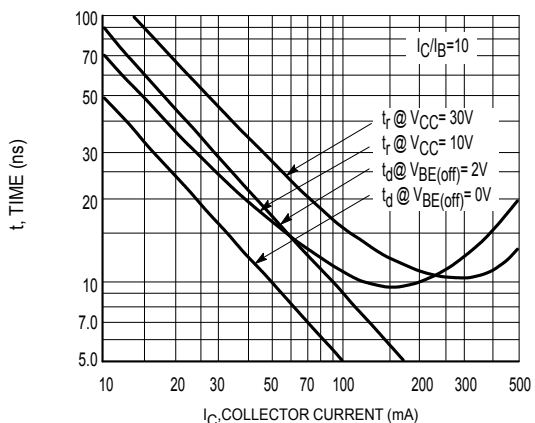


Figure 3. Turn-On Time

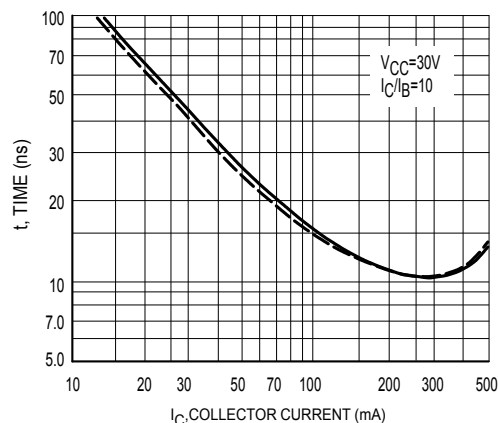


Figure 4. Rise Times

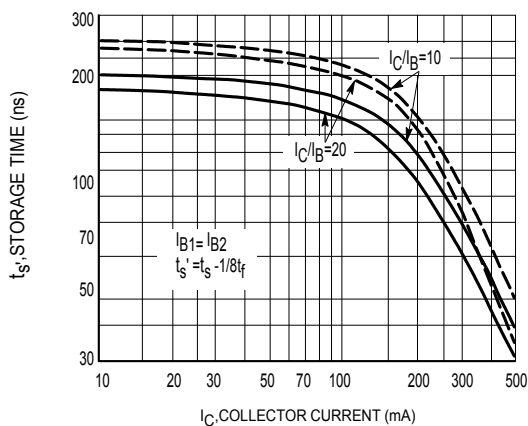


Figure 5. Storage Time

RATING AND CHARACTERISTICS CURVES (2N4403)

$V_{CE} = -10V_{dc}$, $T_A = 25^{\circ}C$

Bandwidth = 1.0Hz

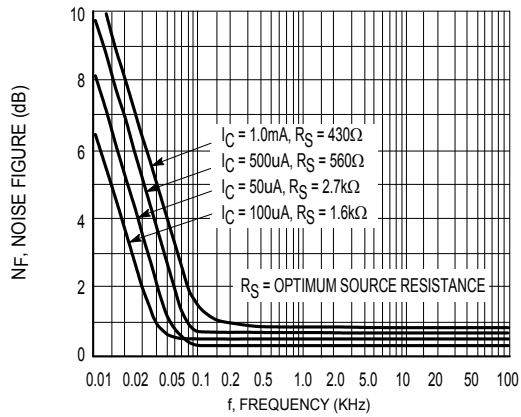


Figure 6. Frequency Effects

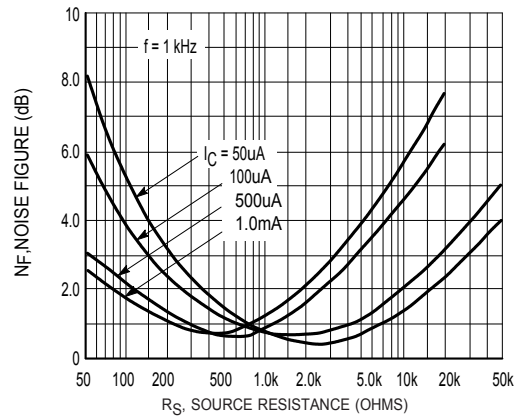


Figure 7. Source Resistance Effects

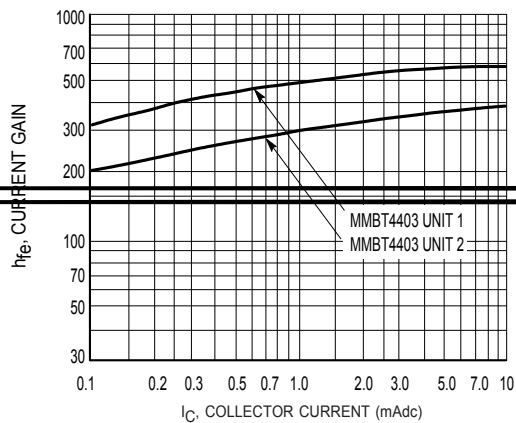


Figure 8. Current Gain

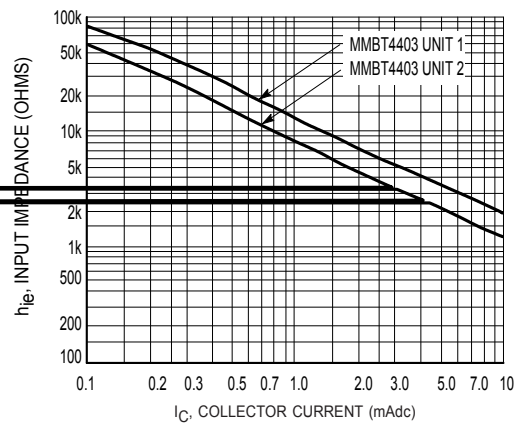


Figure 9. Input Impedance

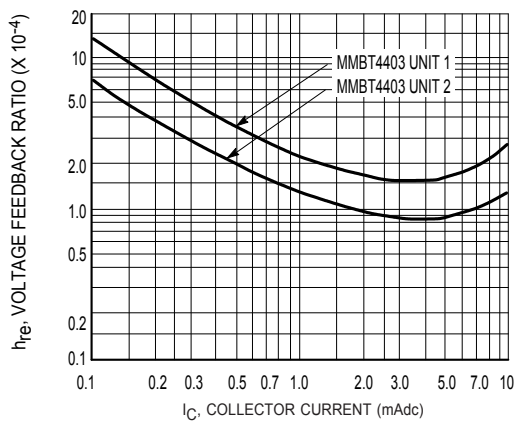


Figure 10. Voltage Feedback Ratio

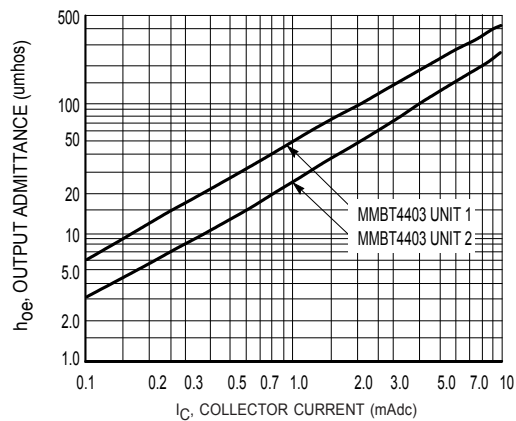


Figure 11. Temperature Coefficients

RATING AND CHARACTERISTICS CURVES (2N4403)

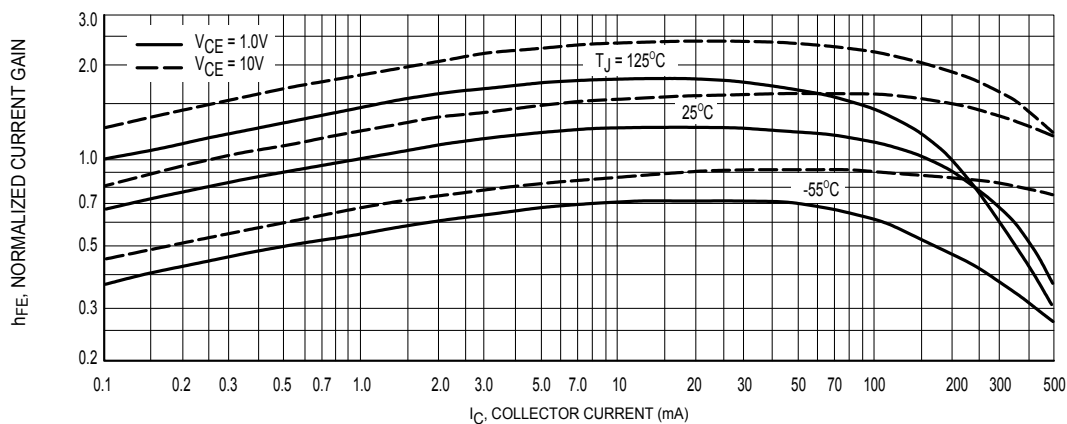


Figure 12. DC Current Gain

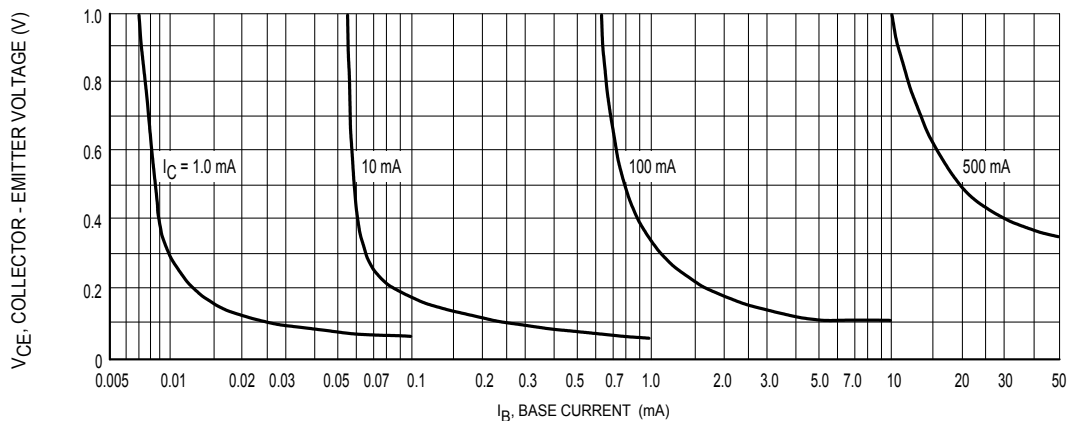


Figure 13. Collector Saturation Region

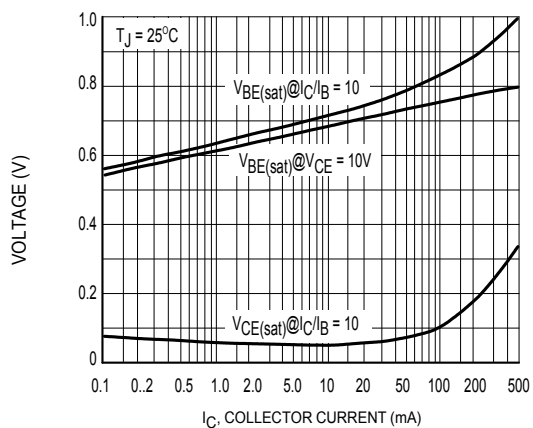


Figure 14. "ON" Voltages

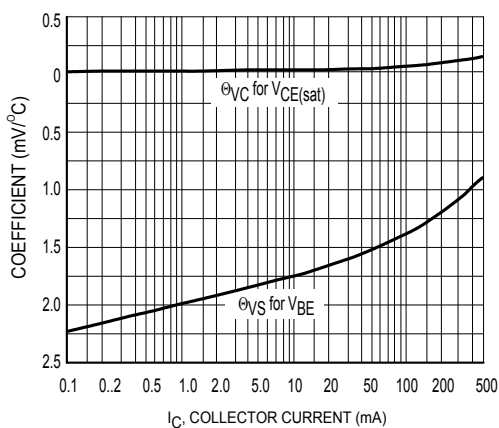


Figure 15. Temperature Coefficients

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